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# A Holistic Study on the Effect of Annealing Temperature and Time on CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>-Based Perovskite Solar Cell Characteristics

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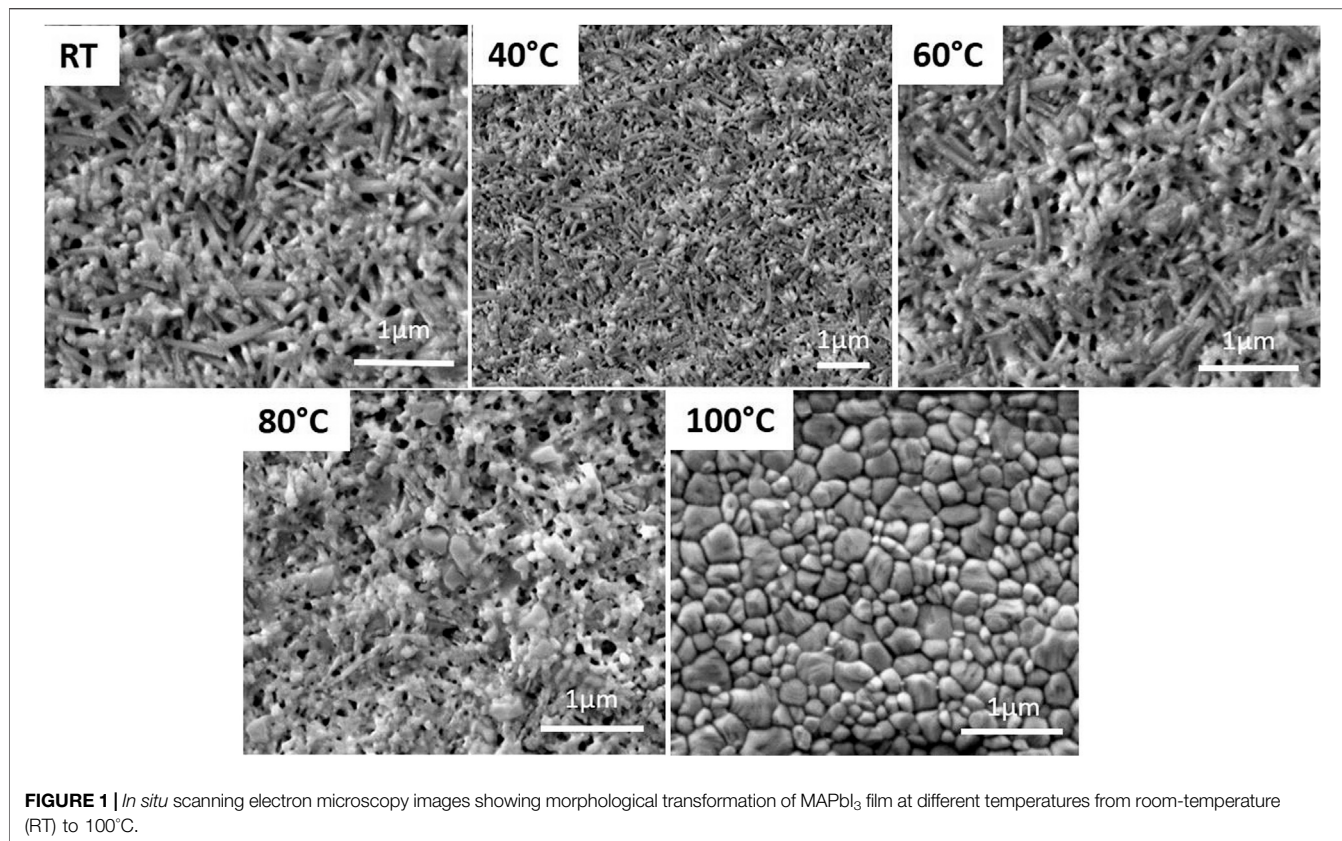
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The time and annealing temperature for the film crystallization in perovskite solar cells (PSCs) is critical and is at the stake of device optimization. It governs the crystallization process, the film's morphology and texture and the level of non-radiative defects, which in whole control the power conversion efficiency (PCE). However, deciphering each of these parameters in the device cell characteristics remains not totally clear. In this work, we led a holistic study considering temperature and time for the MAPbI<sub>3</sub> crystallization as a free parameter to study how the latter is impacting on the film's characteristics and how the device figure of merit is affected. The results suggest that the crystallinity level of the grains plays an important role in the photo-current value whereas the morphology and PbI<sub>2</sub> impurities resulting from the onset of thermal decomposition of MAPbI<sub>3</sub> penalizes the cell photovoltage and the fill factor values. Based on this study, it is highlighted that flash high temperature annealing is beneficial to limit out-of-plane substrate grain boundaries, resulting in a device exhibiting 18.8% power conversion efficiency compared to 18.0% when more standard post-annealing procedure is employed.

**Keywords:** perovskite solar cells (PSCs), annealing temperature, perovskite crystallization, CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> perovskite, holistic study

## INTRODUCTION

Perovskite solar cell (PSC) is today one of the most promising PV technology to reach higher performances in tandem with silicon without impacting drastically on cost production. One feat for PSC lies in the fact that their fabrications are entirely low-temperature and solution-process compatible, constituting a relatively low technical barrier for industrialization. (Galagan, 2018; Li et al., 2018) After less than 10 years of research, power conversion efficiency (PCE) reached as high as 25.5% under standard AM1.5G conditions, thus approaching the thermodynamic Shockley-Queisser limit. (Best Research-Cell Effici, 2019) This remarkable achievement is intimately related to their exceptional optoelectronic properties gathering panchromatic light absorption with high absorption coefficient ( $\epsilon \approx 8,000 \text{ cm}^{-1}$ ), the low effective mass of electrons and holes and low exciton binding energy (Brenner et al., 2015; D'Innocenzo et al., 2014; Shi et al., 2015a; Shi et al., 2015b; Johnston and Herz, 2016; Xing et al., 2013), leading to long-lived and long diffusion length of the dissociated carriers. PSC is highly defective tolerant, however as common with other PV technologies, it is crucial to abate native bulk and surface punctual defects created during crystallization and grain growth



**FIGURE 1** | *In situ* scanning electron microscopy images showing morphological transformation of MAPbI<sub>3</sub> film at different temperatures from room-temperature (RT) to 100°C.

steps to reach highly performant devices. The formation of these defects is closely related to internal and external conditions, as for instance the experimental procedure which can be in principle easily reproduced and more on know-how surroundings that are by nature more complex to duplicate. These defects are at the origin of shallow sub-bandgap states responsible for non-radiative energy losses through carriers cooling. (Nie et al., 2015)

The experimental procedure to fabricate the device largely conditions the film's morphology, grain size, grain boundaries characteristics and the film's stoichiometry which correlate with the type and level of punctual defects. (Saliba et al., 2016; Saliba et al., 2018; Kim et al., 2019) For small devices, the spin-coating technique led so far to the best power conversion efficiency (PCE). (Jeong et al., 2021) Surfactant and/or Lewis base additives introduced into the perovskite precursor solution are common strategies for promoting grain growth and on the other hand leveraging non-radiative recombination pathways by passivating bulk and surface defects. (Liu et al., 2019a; Choi et al., 2020; Liu et al., 2020; Zhang and Zhu, 2020)

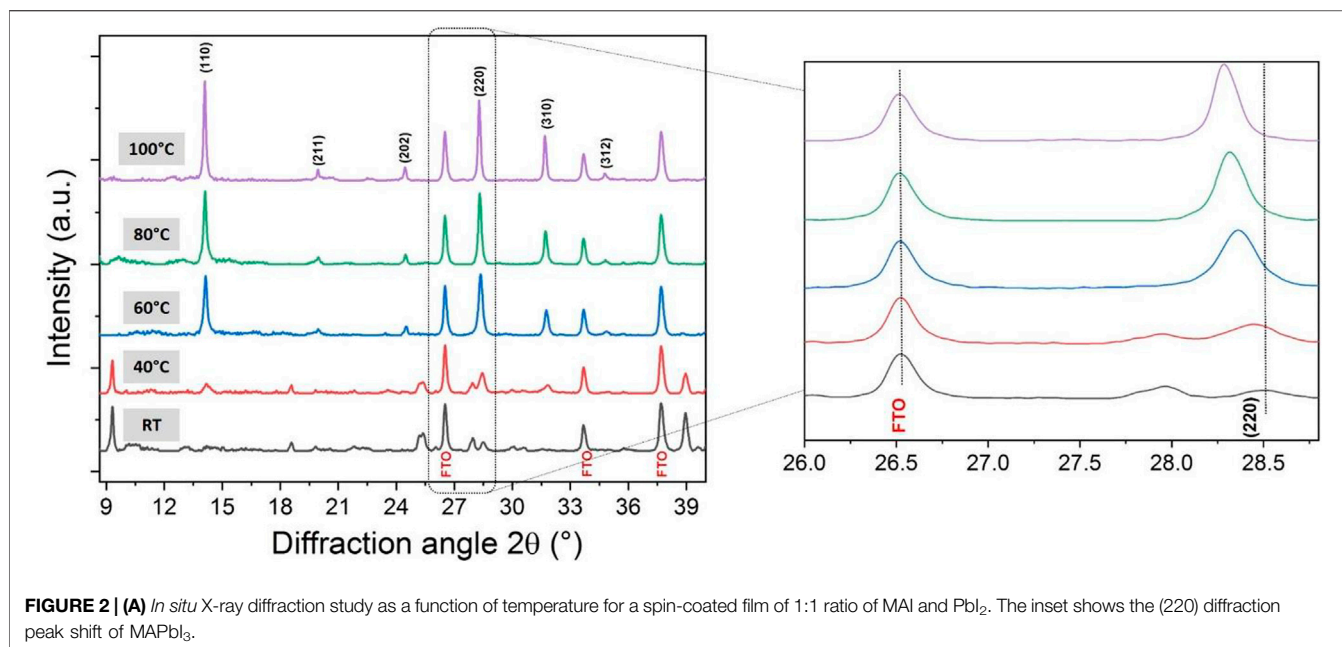
Time and annealing temperature for the film crystallization are critical parameters, that are well-established in the literature. (Dualet et al., 2014; Eperon et al., 2014; Aharon et al., 2015; Liu et al., 2019b; Hsiao et al., 2019) However, a holistic study correlating crystallization temperature, film's texture and morphology, optoelectronic properties and device performance remain an important asset to gain more general insights about how these parameters affects the perovskite film property. In this

work, we focused on the archetypical CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> (MAPbI<sub>3</sub>) and correlate the film's properties depending on the crystallization parameters based on *in situ* and *ex situ* experiences using X-ray diffraction, scanning electron microscopy, steady-state and time-resolved spectroscopies.

## RESULTS AND DISCUSSION

### *In situ* Scanning Electron Microscopy and Observation of Perovskite Formation

*In situ* environmental scanning electron microscopy (SEM) with temperature controller was carried out to visualize the morphological transformation of the film during crystallization (Figure 1). For this, the freshly spin-coated film was transferred from the argon-filled glovebox to the SEM without air exposure using a specifically developed sample transfer tool filled with argon. The as-deposited film's morphology exhibits a very homogeneous and randomly oriented needle-like particles. The needles are about 1 μm in length and 100 nm in width, with a well-visible porosity between the particles. No morphological changes are observed for temperatures below 60°C, even with a prolonged annealing time. From this temperature, we start visualizing the onset of particles transformation from needles to a grain-like morphology which becomes more evident beyond 80°C. These grains are submicrometric, less homogeneous in size and are coexisting with the needles. However, one can



**TABLE 1 |** Evolution of the crystallite size of  $\text{MAPbI}_3$  as a function of the annealing temperature (*in situ*) from room-temperature (RT) to 100°C.

Temperature	RT	40°C	60°C	80°C	100°C
Crystallite size	-	27 nm	60 nm	68 nm	123 nm

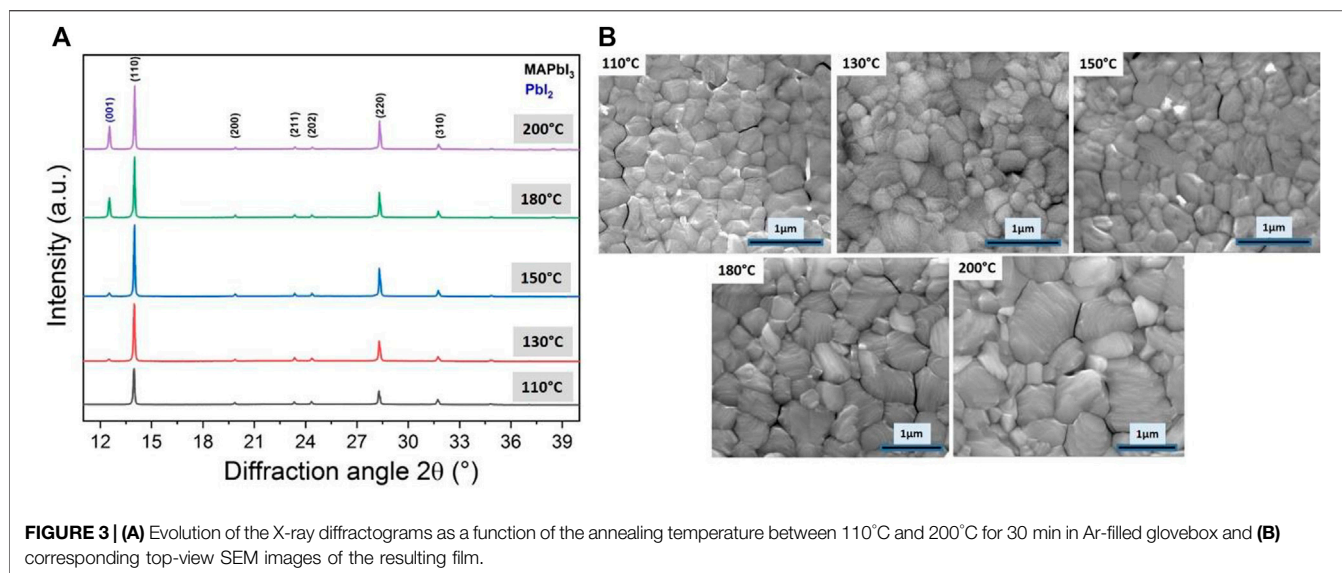
notice that the particles have a less well-defined morphology for the latter. The particles transformation accelerates between 80°C and 100°C even though both types of particles remain in coexistence. The complete transformation into spheroidal and well-packed grains requires a temperature of at least 100°C. From this temperature, the film's morphology corresponds very well to the one typically encountered in literature which affords higher power conversion efficiencies. (Haque et al., 2020)

This *in situ* SEM experiment was corroborated by *in situ* X-ray diffraction study as a function of temperature to determine the film's structural change (Figure 2). The first X-ray diffraction pattern, recorded at room temperature, shows four prominent diffraction peaks at  $2\theta = 9.33^\circ$ ,  $18.59^\circ$ ,  $25.30^\circ$  and  $39.95^\circ$  in addition to those corresponding to the FTO-based glass substrate. These diffraction peaks cannot be ascribed to the tetragonal  $I4/mcm$  space group of  $\text{MAPbI}_3$  phase at room temperature, (Whitfield et al., 2016) nor to  $\text{PbI}_2$  or MAI used as precursors. They are attributed to the formation of an intermediate phase involving the precursors and the solvent (DMF/DMSO). (Jo et al., 2016) Although there is no clear morphological change as seen by SEM, heating to above 40°C causes modification in the film's structure, i.e. decrease of the intermediate phase in favour of the formation of the perovskite structure with the onset growth of the (110), (220) and (310) reflections. These diffraction peaks are becoming narrower and more intense above 60°C. The film crystallizes with a preferential

orientation along the (hh0) planes as often observed in the literature. (Docampo et al., 2014; Song et al., 2015) This direction corresponds to the denser plane of the perovskite structure containing lead and iodide slabs. Table 1 gathers the evolution of the crystallite size corresponding to the (110) direction as a function of the annealing temperature using Scherrer equation. The lanthanum hexaboride was used as a standard sample (no strain or size broadening) to subtract the instrumental broadening contribution from the FWHM. A slight shift to lower angles of the (hh0) diffraction peaks is observed due to thermal expansion of the perovskite lattice with the temperature (Figure 2).

In addition to these *in situ* investigations, providing direct insights on the early-stage processes on film's crystallization and morphological change, *ex situ* experiments combining XRD and SEM analysis were also performed to cover the range of temperatures above 100°C (Figure 3). For this, the annealing process was carried out for 30 min in an Ar-filled glovebox, corresponding to the typical crystallization method reported in the community to reach a film with a high optical quality.

The temperature increase leads to a stronger preferential orientation along (hh0) planes family coming concomitantly with a narrowing of the (110) diffraction peak, which results from larger crystallite size reaching 210 nm for this out-of-plane direction (Table 2). This observation correlates well with the top view SEM image showing well-visible grain growth in-plane of the FTO glass substrate (Figure 3B). The commonly shared wisdom regarding film's morphology is that larger grains are beneficial for the device performances. (Choi et al., 2020) It limits the number of grain boundaries, which are one seat for non-radiative recombination losses due to shallow surface traps. (Gao et al., 2019a) Surface defects, including grain boundaries, play a significant role in the moisture-induced degradation of  $\text{MAPbI}_3$ . (deQuilettes et al., 2017; Akhavan Kazemi et al., 2020; Krishna



**TABLE 2 |** Evolution of crystallite size, the ratio between (110) and (202) diffraction peak intensities and the ratio between (110) of MAPbI<sub>3</sub> and (001) of PbI<sub>2</sub> as a function of the annealing temperature of MAPbI<sub>3</sub> films annealed between 110–200 °C.

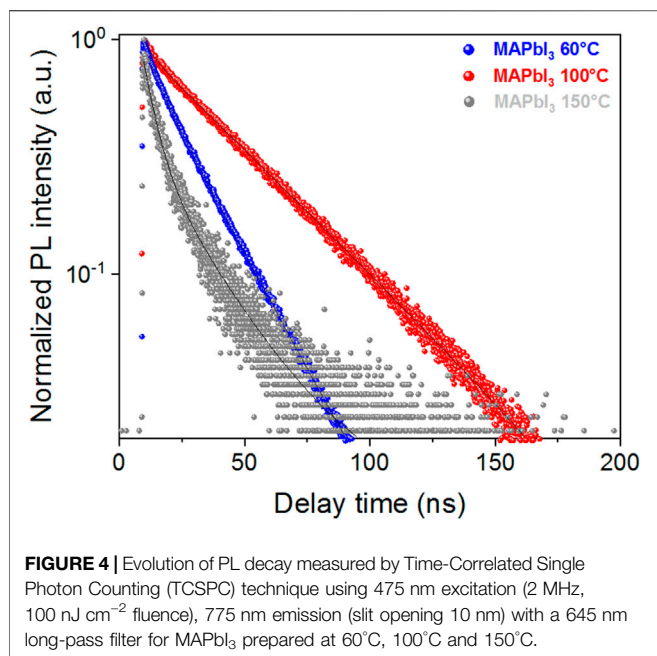
Temperature	110°C	130°C	150°C	180°C	200°C
Crystallite size	170 nm	167 nm	203 nm	206 nm	210 nm
Ratio I(110)/I(202)	10	14.6	17.9	16.2	20.0
a parameter (Å)	8.8716 (2)	8.8715 (2)	8.8674 (3)	8.8696 (8)	8.8706 (1)
c parameter (Å)	12.655 (1)	12.639 (1)	12.649 (1)	12.669 (1)	12.652 (1)
cell volume (Å <sup>3</sup> )	996.0 (1)	994.8 (1)	994.6 (1)	996.6 (1)	995.6 (1)

et al., 2020) Limiting the number of grain boundaries within the film's thickness is primordial to ensure efficient carriers collection. (Xiao et al., 2014; Li et al., 2016; Gao et al., 2019b) Therefore, a film's preferential orientation along (hh0) planes combined with high uniformity and larger grain size would be beneficial for higher diffusion length of the photo-generated carriers towards the selective contacts, which is one important feature for high photovoltaic performances. (Leblebici et al., 2016; Zhang et al., 2016)

However, although higher annealing temperatures still improve the film's quality, increasing the annealing temperature to above 130°C leads to the onset of a competitive process niche in a decomposition reaction leading to PbI<sub>2</sub> in the film ( $2\theta = 12.69^\circ$ ) and MAI gas release. This reaction is facilitated by the high volatility of methylammonium iodide at this temperature. Slight modifications of the lattice cell parameters are observed depending on the post-annealing temperature leading to a cell volume in the range of 996 Å<sup>3</sup>. This slight fluctuations indicate that the bulk film stoichiometry may vary slightly.

The influence of the post-annealing temperature on the films' optical characteristics was evaluated by UV-Visible absorption spectroscopy (**Supplementary Figure S1**). For all temperatures, the as-prepared MAPbI<sub>3</sub> films exhibited a strong light absorption from 400 to 780 nm, indicating panchromatic light harvesting. A

sharp increase in absorbance is observed, starting from 40°C to higher temperatures which is associated visually to a transition from a brown semi-transparent to a black mirror feature. At RT and 40°C, we can notice an absorption band at 400 nm. It is attributed to the unreacted precursors and/or the coordinated intermediate phase involving PbI<sub>2</sub> and the solvent (DMF/DMSO), in agreement with the XRD peak at  $2\theta = 9.33^\circ$  showed in **Figure 2**. Upon increasing the temperature to 140°C, a noticeable increase in the optical absorbance of MAPbI<sub>3</sub> (below ca. 600 nm) is observed. For higher temperatures, it decreases by about half magnitude owing to the formation of the yellow PbI<sub>2</sub> phase. The optical bandgap, deduced from the tauc plot (**Supplementary Figure S2**), narrows slightly from 1.60 eV for the temperatures below 100°C, 1.59 eV for the temperature range between 100°C and 180°C and reaches 1.58 eV at 200°C (**Supplementary Table S1**). The PL spectra also show slight but visible variations between 770 and 780 nm depending on the post-annealing temperature. The full width at half maximum of the PL band becomes narrower when crystallized, more symmetrical and more intense with temperature. However, this is associated with an increase of Urbach energy from 59.5 to 103.5 meV with the temperature, thus indicating that the latter causes more surface electronic disorder which may affect the photovoltage and fill factor values.



The radiative recombination dynamic of MAPbI<sub>3</sub> depending on the annealing temperature has been studied using Time-Correlated Single Photon Counting (TCSPC) technique (Figure 4). This study has been carried out on a film deposited upon glass substrate. For the sake of clarity, we herein selected three type of films. One for an annealing temperature of 100°C, one at a lower temperature (i.e. 60°C) which represents a pivotal temperature for the film crystallization as abovementioned, and a last one at a higher temperature (i.e., 150°C) which represents a region where PbI<sub>2</sub> starts to be formed.

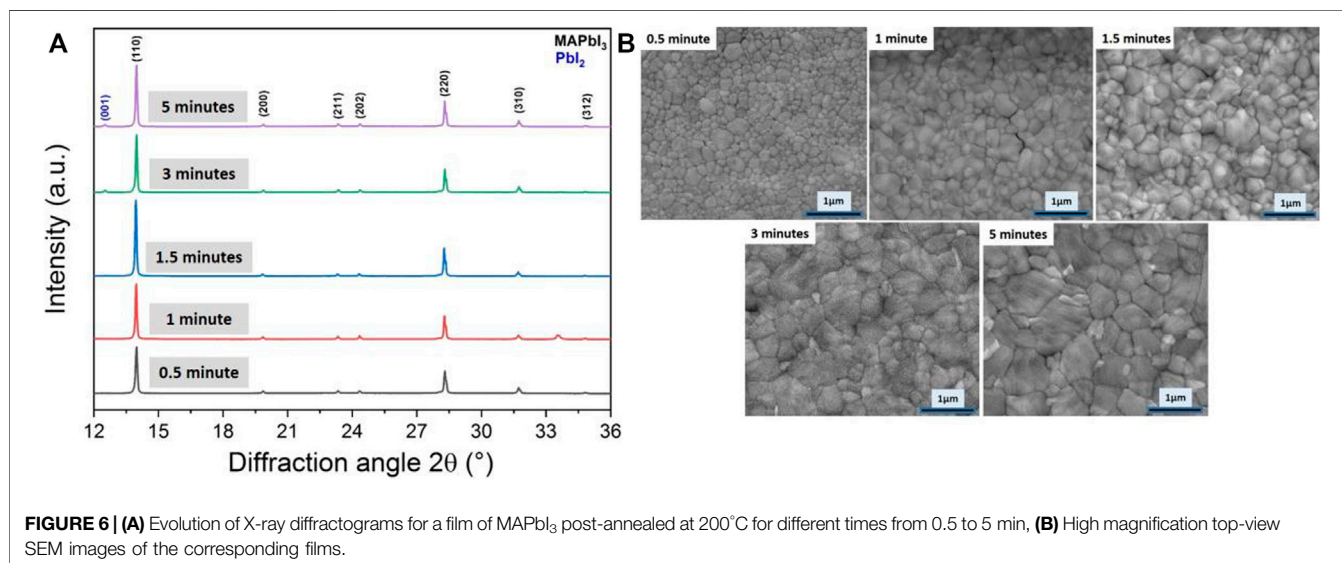
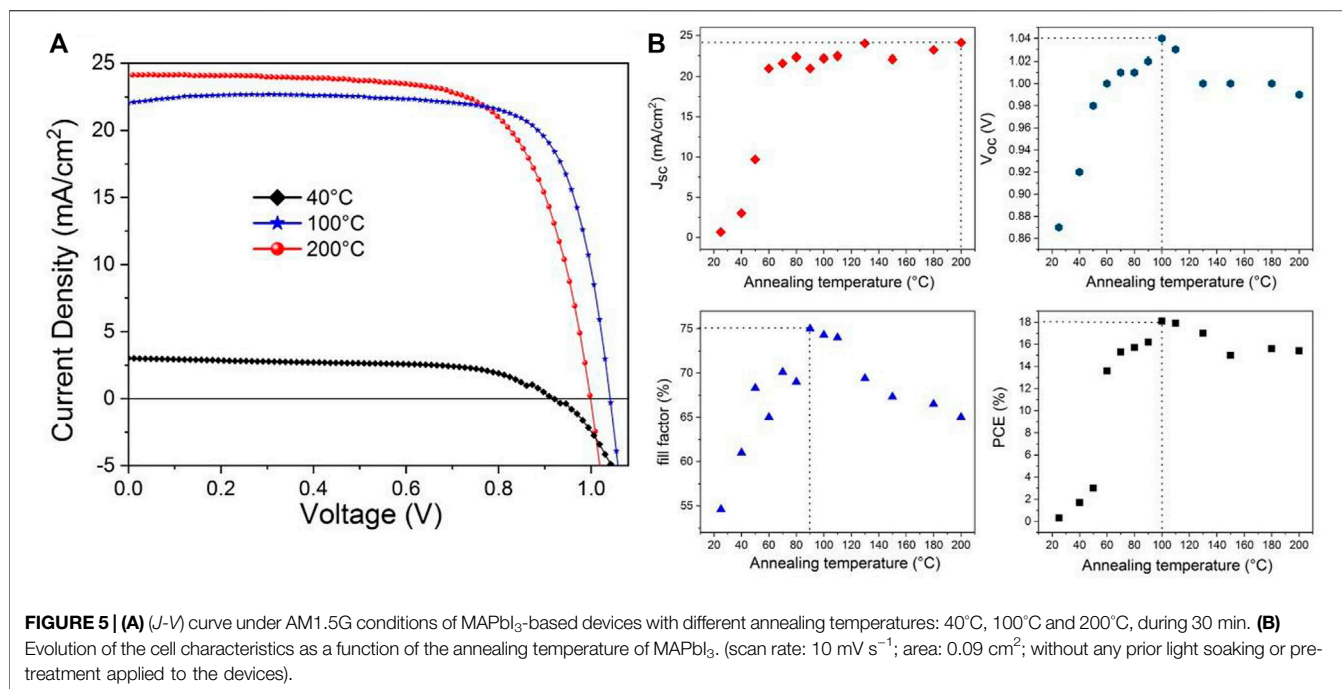
For the film prepared at 100°C, the PL decay is very close to a mono-exponential feature. It has a minor contribution of 8% in fraction leading to a  $\tau_1 = 4.2$  ns and a predominant slower contribution  $\tau_2 = 41.4$  ns. This leads to an average lifetime  $\langle\tau_{\text{avg}}\rangle = 38.4$  ns (Table 3). Two contributions have been largely reported in the literature. (Son et al., 2016; Lee et al., 2017) Based on literature and our previous observations (Akhavan Kazemi et al., 2020), the fast component is attributed to the dynamic of carriers trapping at the surface and/or at the grain boundaries. The latter is largely influenced by the laser fluence, surface passivation and the interface between the perovskite grains and the environment. The slow component corresponds to the Shockley-Read-Hall recombination dynamic in bulk. For the film prepared at lower temperature, a single exponential decay is observed with a half-time of  $\tau = 18.2$  ns. For

higher temperature, the PL decay becomes more clearly bi-exponential with the predominance of the fast component with same half-time; i.e.,  $\tau_1 = 4.3$  ns ( $f = 62\%$ ) and a slow contribution  $\tau_2 = 20.3$  ns ( $\langle\tau_{\text{avg}}\rangle = 10.5$  ns). For this film, the PL yield is reduced which is at the origin of the dispersity in the data points. These results suggest that PbI<sub>2</sub> as a degradation by-product and higher annealing temperatures create surface/grain boundaries carriers trapping and accelerate the radiative bulk recombination despite the formation of larger grains as observed by SEM. This result correlates with the Urbach energy increases.

The impact of the annealing temperature on the device performance has been investigated in a n-i-p mesoscopic cell configuration. Figure 5 gathers the (*J*-*V*) curves of the champion cell for the perovskite layer prepared at 100°C and for the two extremum temperatures, and, the evolution of the cell characteristics as a function of the post-annealing temperature. The different characteristic values are reported in Supplementary Table S2. The annealing process was carried out for 30 min. The results show primarily two domains. The first lies between room-temperature and 60°C. In this range, both the cell photovoltage and photocurrent are increasing very rapidly with temperature. This correlate with the noticeable morphological evolution and perovskite structure crystallization as aforementioned. The cell photovoltage reaches a maximum of 1.04 V for an annealing temperature of 100°C. Below and above this temperature, the open circuit voltage is in the range of 1.00 V, except when the perovskite film is not crystallized even though the latter still exhibits a remarkable value of around 0.90 V. By contrast to the deliberate introduction of PbI<sub>2</sub> excess in the precursor solution leading to PbI<sub>2</sub> grains in the film and located at grain boundaries which are reported to alleviate surface defects, when the latter is issued from MAPbI<sub>3</sub> decomposition, its consequence into the device performance is totally different. It does not produce any photovoltage gain. In opposite, it decrease the latter owing to more defects creation. A similar evolution is observed for the fill factor, at the exception of the maximum that is reached at a temperature of 90°C. Well-crystallized, large and defective-free grains of MAPbI<sub>3</sub> are key parameters to reach higher fill factor and photovoltage values as herein suggested. Interestingly, besides for the amorphous film, the cell photocurrent is a parameter much less sensitive to the annealing temperature. Our devices generate in average a photocurrent value of ca. 22.5 mA/cm<sup>2</sup> with a maximum of 24.0 mA/cm<sup>2</sup> for the film crystallized at 130°C and 200°C (Figure 5B). The statistical analysis is shown in Supplementary Figure S3. This result led us to the conclusion that the film's crystallinity plays the major role for the photocurrent generation and is not drastically affected by the formation of PbI<sub>2</sub> subsequently to the thermal decomposition of MAPbI<sub>3</sub>.

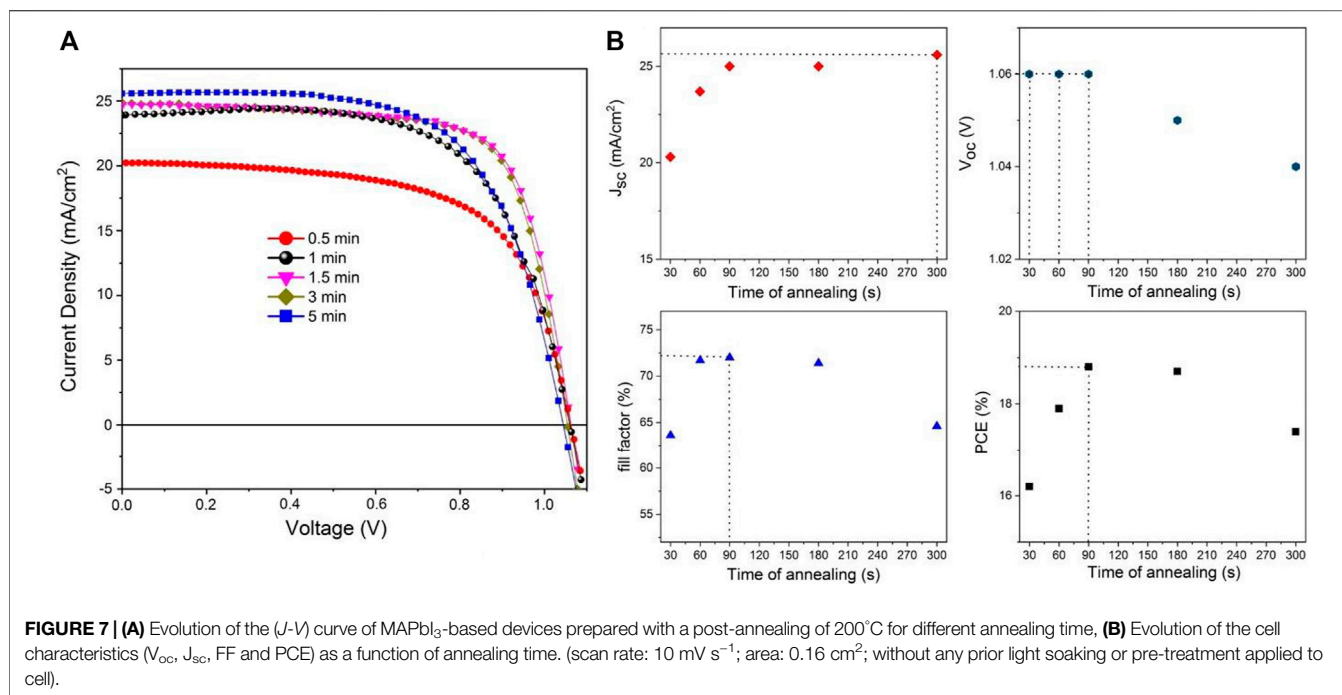
**TABLE 3** | Summary of the PL characteristics obtained after reconvolution from IRF for MAPbI<sub>3</sub> depending on the crystallization temperature.

	$\alpha_1$ (%)	$\tau_1$ (ns)	$A_1$	$\alpha_2$ (%)	$\tau_2$ (ns)	$A_2$	$\tau_{\text{avg}}$ (ns)
MAPbI <sub>3</sub> 60°C	100	18.2	1,560	-	-	-	18.2
MAPbI <sub>3</sub> 100°C	8	4.2	981	92	41.4	1,136	38.4
MAPbI <sub>3</sub> 150°C	62	4.3	4,407	38	20.3	600	10.5



This work underlines the existing temperature trade-off between increasing the post-annealing temperature for promoting large, well-packed and well-crystallized MAPbI<sub>3</sub> grains and onset of its thermal decomposition into PbI<sub>2</sub> in the film and MAI releases. With the aim to explore a protocol to combine the best of the high temperature annealing, we investigated the effect of time for a post-annealing temperature of 200°C from 30 s to 5 min. Surprisingly, a post-annealing of only 30 s affords to have pinhole-free and well-crystallized MAPbI<sub>3</sub> film (Figure 6). Although it has been discussed in literature that a very fast crystallization of

MAPbI<sub>3</sub> can be beneficial to form randomly oriented grains (Dong et al., 2015), in our case, the results show already a strong preferential orientation of the grains along (110) direction. Prolonging the annealing time leads to grain growth from ca. 200 nm to more than 1 μm as showed by the top-view SEM pictures (Figure 6B). Sharper diffraction peaks are also experienced with time. The crystallize size is increasing from 152 to 222 nm along the (110) direction without affecting significantly the preferential orientation. PbI<sub>2</sub> formation starts after ca. 3 min (Figure 6A). The PbI<sub>2</sub> nanoparticles are well-visible on the SEM pictures leading to



**TABLE 4 |** Summary of the cell characteristics measured under AM 1.5G conditions for MAPbI<sub>3</sub> films crystallized at 200°C for different annealing time.

Annealing time (min)	$V_{oc}$ (V)	$J_{sc}$ (mA/cm <sup>2</sup> )	FF (%)	PCE (%)
0.5	1.06	20.3	63.6	16.2
1	1.06	23.7	71.7	17.9
1.5	1.06	25.0	72.0	18.8
3	1.05	25.0	71.4	18.7
5	1.04	25.6	64.6	17.4
10	1.00	26.3	64.4	17.2

bright and small nanocrystals of ca. 100 nm size. They are principally formed at grain boundaries between the MAPbI<sub>3</sub> grains and we hypothesized that there are formed preferentially on top of the film and not inner considering the difficulties to release MAI from bulk (**Figure 6B**).

The evolution of steady-state PL for the different annealing time shows that the highest intensity is obtained for 1.5 min with a maximum of PL at 780 nm (**Supplementary Figure S4**). For longer time, the PL rapidly drop, thus suggesting that extended exposure irreparably causes the formation of non-radiative recombination pathways, likely bulk/surface shallow traps. As for temperature effect, lower crystalline perovskite leads to a broad and blue-shifted emission at ca. 770 nm.

As one could expect, there is an important influence of the annealing time on the photovoltaic performances (**Figure 7**; **Table 4**). The best PCE is obtained for a post-annealing time of 1.5 min leading to a value of 18.8% under AM1.5G conditions ( $V_{oc} = 1.06$  V,  $J_{sc} = 25.0$  mA/cm<sup>2</sup> and FF = 72.0%). These values are improved compared to the conventional and milder annealing temperature of 100°C for 30 min, thus highlighting

the relevance of examining flash post-annealing procedure. This is actually the best compromise found between large perovskite grains, low level of non-radiative defects while avoiding perovskite decomposition into PbI<sub>2</sub>. Based on the cell characteristics evolution, we support similar conclusions as above, namely the low crystallinity mainly affects the cell photocurrent whereas onset of perovskite decomposition into PbI<sub>2</sub> mainly penalizes the cell photovoltage and the fill factor values. The preconceived opinion that the largest grain size from top-view SEM pictures is a guarantee of high device performance is probably simplistic. The level of grain boundaries seems having here limited consequences on the cell photovoltage and the fill factor and the high crystallinity of the grain is a more important factor to consider in agreement with Liu et al. (Ren et al., 2016) Compared to the 100°C for 30 min post-annealing condition, the cross-sectional SEM picture reported in **Supplementary Figure S5** shows that grain boundaries are more perpendicularly oriented to the substrate in the case of this flash annealing. This is finally consistent with the larger crystallite size determined for the [110] direction which reaches 196 nm, a value more comparable to the film's thickness, compared to 123 nm for the first condition.

## CONCLUSION

This holistic study establishes the relationship between the post-annealing temperature and time for the crystallization of MAPbI<sub>3</sub> on the textural, opto-electronic properties and device characteristics under AM1.5G conditions. The textural properties of the perovskite are closely related to the post-



annealing conditions. The latter controls the competitive process between crystal growth and high crystallinity, an important asset to reach high photocurrent value, and MAPbI<sub>3</sub> decomposition into PbI<sub>2</sub> which in turn affects both the cell photovoltage and the fill factor values. Higher temperatures accelerate the formation kinetic of MAPbI<sub>3</sub>, produces a perovskite film with higher crystallinity, stronger preferential orientation along (hh0) planes and larger grains. However, it prompts also its decomposition into PbI<sub>2</sub> and MAI gas release. For temperatures above 130°C for 30 min, this thermal treatment creates non-radiative defects responsible for fill factor and photovoltage decrease. Optimal conditions, considering such two antagonists processes (high crystallinity vs thermal decomposition), were obtained at 100°C for 30 min leading to a device exhibiting 18.0% PCE. However, flash annealing, combining a high post-annealing temperature of 200°C with very short annealing time (1.5 min), leads to a film exhibiting the best textural properties and at same time the highest PCE value of 18.8%. This improvement is mainly attributed to the obtaining of well-crystallized films composed of grains having limited amount of grain boundaries out-of-plane while having not the time to seed the thermal decomposition into PbI<sub>2</sub> and MAI.

## MATERIALS AND METHODS

**Materials:** Unless specified, all chemicals were purchased from Sigma-Aldrich. Mesoporous TiO<sub>2</sub> paste and FK209 were purchased from Greatcell solar materials. PbI<sub>2</sub> and MAI were purchased from TCI.

**Thin film fabrication:** Glass substrate or FTO (TEC11L) were used. They were systematically cleaned with 2 vol% of hellmanex solution in DI water, isopropanol, acetone and treated with UV/O<sub>3</sub> cleaner for 15 min prior being used. The precursor solution was prepared by dissolving 1 mol/L MAI (159 mg), 1 mol/L PbI<sub>2</sub> (461 mg) in anhydrous N,N-dimethylformamide and anhydrous dimethylsulfoxide with 4:1 volume ratio. The solution was kept under stirring overnight at 70°C and then cooled down to ambient temperature. The solution was spin-coated (Laurell Spin coater WS-650hz) according to a two-step procedure inside an Ar-filled glovebox (MBraun Unilab Pro SP), first at 1,000 rpm for 10 s and then at 4,000 rpm for 20 s. During the second step, 1 ml of toluene as an anti-solvent was dropped 10 s before the end of the program. These films were annealed inside the same Ar-filled glovebox at different temperatures and for 30 min. The crystallization of the perovskite structure leads to a mirror-like dark film. This procedure has been optimized to reach the highest power conversion efficiency in full devices.

**Device Fabrication:** FTO glass substrate (NSG10) was cleaned according to the same procedure as aforementioned. A compact TiO<sub>2</sub> blocking layer is deposited by spin-coating using a 0.15 mol/L titanium diisopropoxide bis(acetylacetonate) (75%) in 1-butanol (3,000 rpm for 30 s). The film is annealed at 125°C for

5 min. A second layer is deposited with 0.3 mol/L titanium diisopropoxide bis(acetylacetonate) solution in 1-butanol with same procedure. After this, the substrates were heated at 450°C for 30 min to form a compact layer of TiO<sub>2</sub> of ca. 50 nm thickness. A 200 nm mesoporous TiO<sub>2</sub> layer is deposited by spin coating at 4,000 rpm for 30 s with a ramp of 1,000 rpm s<sup>-1</sup> from the commercially available TiO<sub>2</sub> paste diluted in ethanol (6:1 weight ratio). After spin coating, the substrate is immediately dried at 120°C during 10 min. The substrate is then sintered at 500°C for 30 min before the deposition of the perovskite layer. The precursor solution was prepared by dissolving 1 mol/L MAI (159 mg) and 1 mol/L PbI<sub>2</sub> (461 mg) in anhydrous N,N-dimethylformamide (0.8 ml), and anhydrous dimethylsulfoxide (0.2 ml). These solutions were then spin-coated in a two-step procedure at 1,000 rpm for 10 s and 4,000 rpm for 20 s, respectively. During the second step, 1 ml of toluene was dropped 10 s before the end of the program. These spin-coated perovskite films were annealed at different temperatures for 30 min inside an Ar-filled glovebox.

**Films and Device Characterization:** The (J–V) characteristics were recorded by means of a Keithley computer-controlled digital source meter (2412A) combined with a 3A class Newport SOL3A sun simulator with an AM 1.5G filter (100 mW/cm<sup>2</sup>). The light intensity was calibrated with a NREL-certified KG5-filtered Si reference diode. The photo-active area is 0.09 cm<sup>2</sup> defined by a 3D printed black mask. The scan direction is reverse.

X-ray diffraction study was carried out at room temperature on a Bruker D8 diffractometer using a copper anti-cathode ( $\lambda_{\text{CuK}\alpha 1}=1.54056 \text{ \AA}$  and  $\lambda_{\text{CuK}\alpha 2} = 1.54439 \text{ \AA}$ ) and LynxEye detector. Each patterns were collected in 30 min between  $2\theta = 10^\circ$  to  $40^\circ$  with a step size of  $0.01^\circ$ . The *in situ* measurement was carried out using an Anton Paar HTK furnace.

Scanning electron microscopy images were obtained using an environmental FEI Quanta 200 FEG microscope. Freshly spin-coated and not-annealed film was transferred from argon-filled glovebox into the SEM chamber and high vacuum operating condition established. During the transfer, the film was kept inside a transferring argon-filled box. The morphological evolution was followed *in situ* by gradually increasing the temperature of the sample holder. The UV-Visible absorption spectra were recorded in transmittance mode using an Agilent Cary5000 UV-Vis-NIR spectrometer. TCSPC experiments were carried out on Edinburgh Instrument FLS980 spectrometer using picosecond 475 nm laser diodes as an excitation source (2 MHz, 100 nJ cm<sup>-2</sup> fluence), at 775 nm emission with a 645 nm long pass filter and slit size of 10 nm. A microchannel plate photomultiplier tube (MCP-PMT) Hamamatsu detector is set after the first emission monochromator. The measurements were carried out in front-face configuration. The typical instrument response function (IRF) value in this configuration is ca. 80 ps. The steady-state PL spectra were measured using the same spectrometer with a continuous xenon arc lamp (450 W) equipped with a double excitation and double emission

monochromators to reach stray light rejection less than  $10^{-10}$  (excitation/emission bandwidth of 3 nm). The samples were excited at 450 nm and the emission detected by a high-gain photomultiplier tube (PMT) detector mounted after the second emission monochromator. For both steady-state PL and TCSPC measurements, the perovskite film was deposited on a clean glass substrate, and the samples were excited front to the perovskite layer.

The PL decays were fitted, after reconvolution from the IRF, using either a mono-exponential function or when needed a bi-exponential function to account from traps filling in the form of :

$$I = A_1 e^{-t-t_0/\tau_1} + A_2 e^{-t-t_0/\tau_2}. \quad (1)$$

where  $\tau_1$  and  $\tau_2$  are the half-time constants, and  $A_1$  and  $A_2$  are their corresponding pre-exponential factors. The average lifetime is obtained as following:

$$\langle \tau_{avg} \rangle = \alpha_1 \tau_1 + \alpha_2 \tau_2. \quad (2)$$

where,  $\alpha_i = \frac{A_i \tau_i}{\sum_{n=1}^{n=i} A_n \tau_n}$ .

## DATA AVAILABILITY STATEMENT

The original contributions presented in the study are included in the article/**Supplementary Material**, further inquiries can be directed to the corresponding author.

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## AUTHOR CONTRIBUTIONS

MK conducted most of the experiments and provided first draft of the article. AJ assisted MK for the *in situ* SEM experiments. FS has supervised the work and finalized the article.

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## SUPPLEMENTARY MATERIAL

The Supplementary Material for this article can be found online at: <https://www.frontiersin.org/articles/10.3389/fenrg.2021.732886/full#supplementary-material>

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